Flash Memory Overview

Steven Swanson

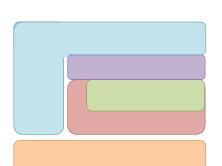
Welcome to the Data Age

- The world processed 9
 Zettabytes of data in
 2008*
- Acquiring data is easy
- Extracting knowledge is hard
 - Storage performance is major bottleneck
 - Solid-state storage can help

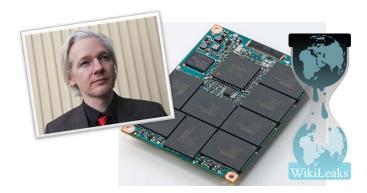




Hardware/Software Prototyping



Programming interfaces



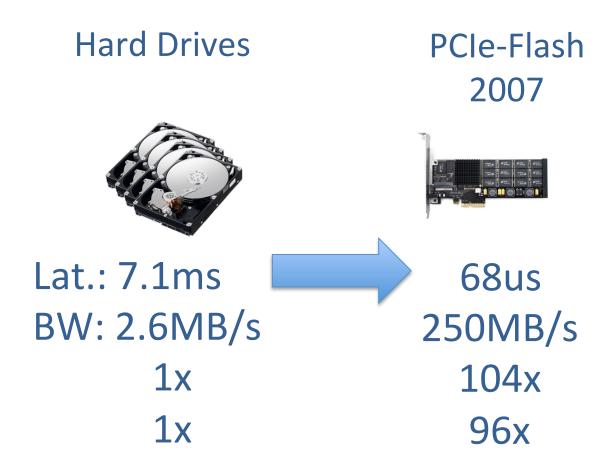
Data Security



The Flash Juggernaut

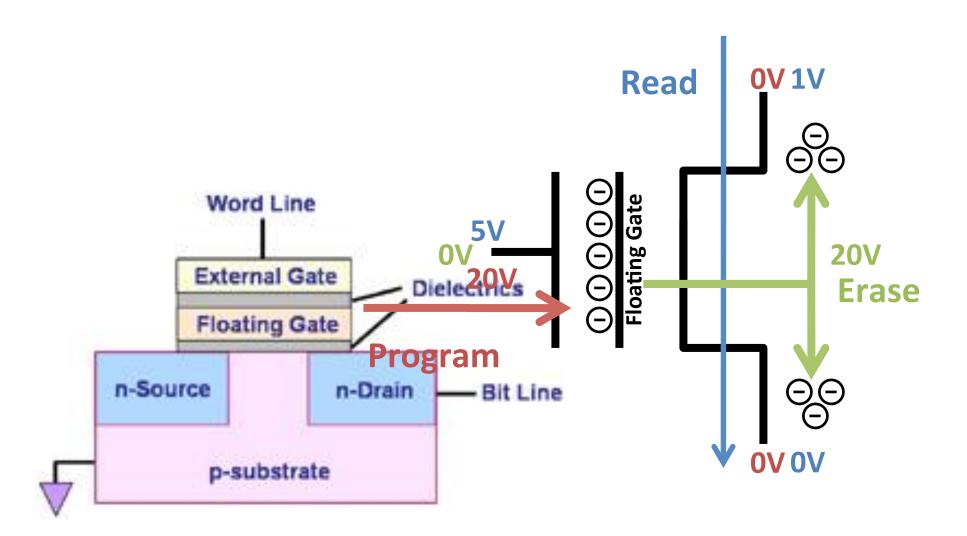


Flash is Fast!

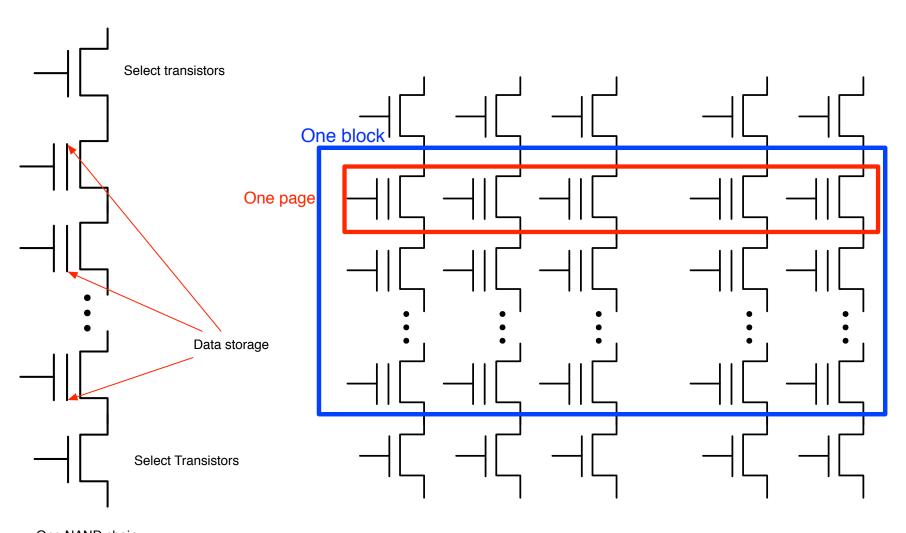


Random 4KB Reads from user space

Flash Operations

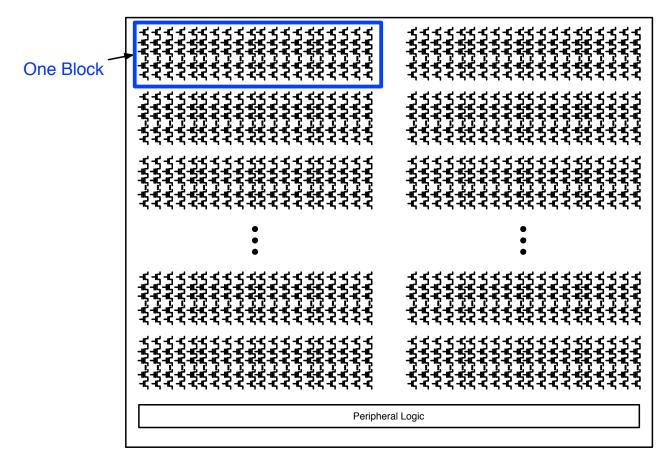


Organizing Flash Cells into Chips



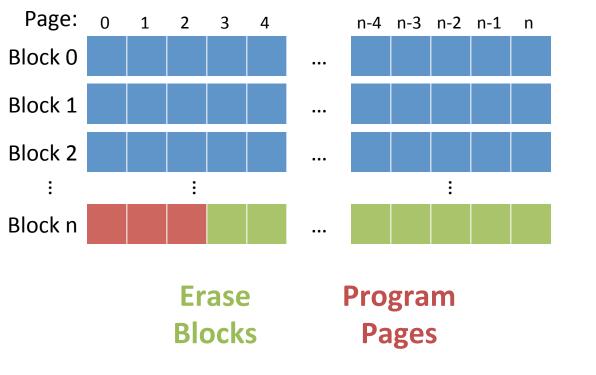
One NAND chain

Organizing Flash Cells into Chips



- ~16K blocks/chip
- ~16-64Gbits/chip

Flash Operations

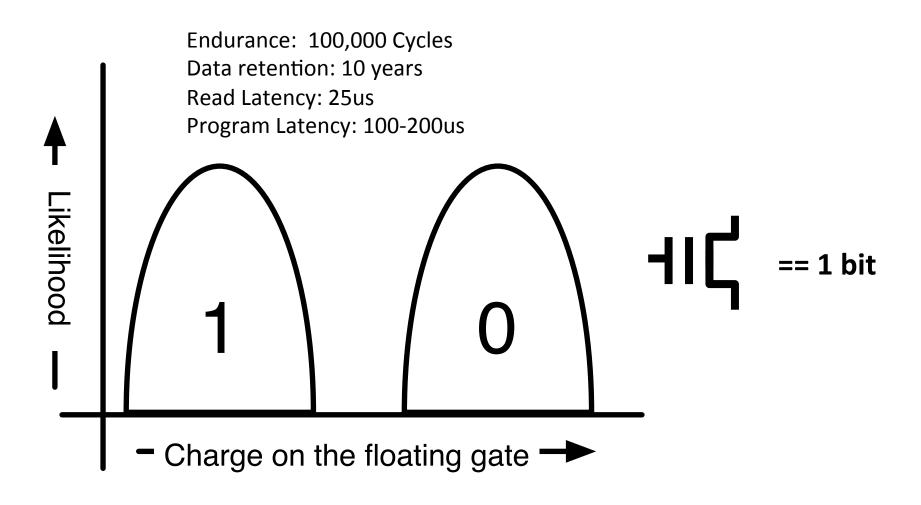


SLC: Single Level Cell

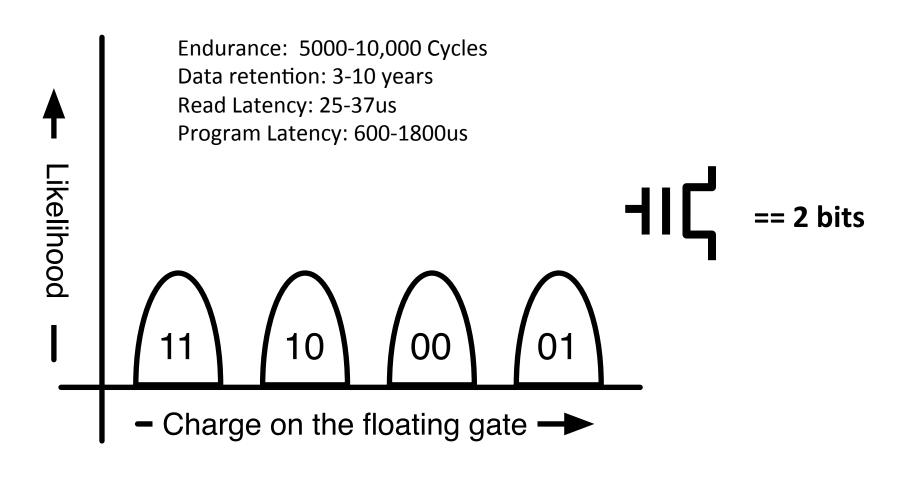
MLC: Multi Level Cell

TLC: Triple Level Cell

Single-Level Cell



Multi-Level Cell (2 bits)

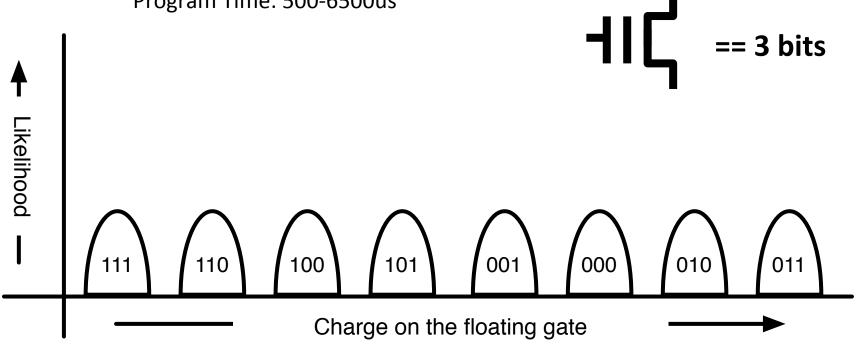


Triple-level Cell (3bits)

Endurance: ~500-1000 Cycles

Data retention: 3 years Read Time: 60-120us

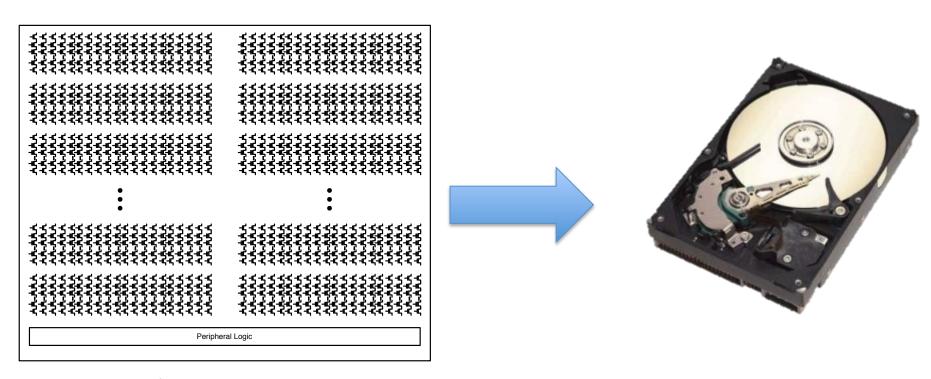
Program Time: 500-6500us



Flash Failure Mechanisms

- Program/Erase (PE) Wear
 - Permanent damaged to the gate oxide at each flash cell
 - Caused by high program/erase voltages
 - Damage causes charge to leak off the floating gate
- Program disturb
 - Data corruption caused by interference from programming adjacent cells.
 - No permanent damage

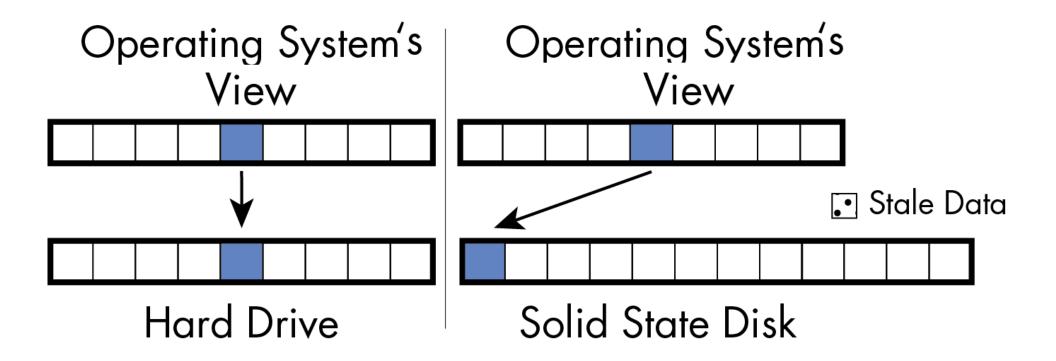
Making Disks out Flash Chips



Read Pages Write Pages Erase Blocks Hierarchical addresses PE Wear

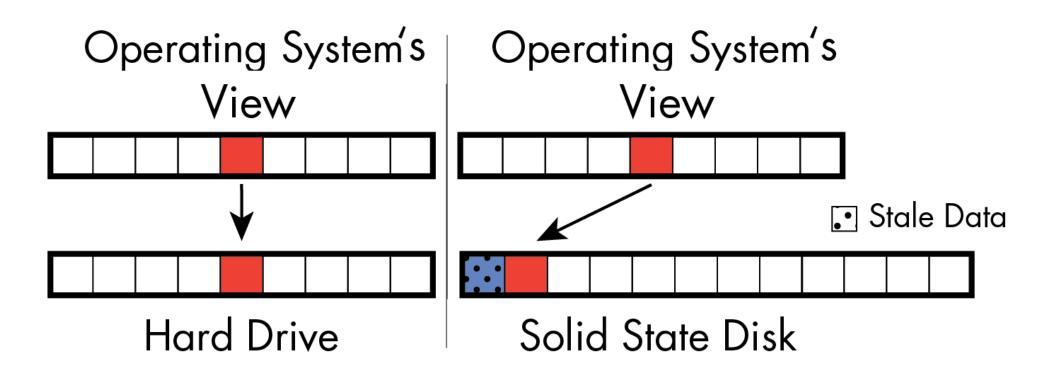
Read Write Flat address space No wear limitations

Writing Data



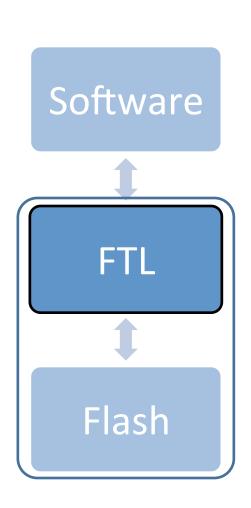
SSD Maintain a map between "virtual" logical block addresses and "physical" flash locations.

Writing more data...



When you overwrite data, it goes to a new location.

Flash Translation Layer (FTL)



User

Logical Block Address

Flash

- Write pages in order
- Erase/Write granularity
- Wears out

FTL

- Logical

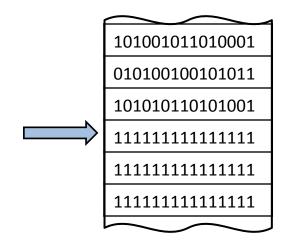
 Physical map
- Wear leveling
- Power cycle recovery

Centralized FTL State

Map

LBA	Physical Page Address		
0	Block 5	Page 7	
2k	Block 27	Page 0	
4k	Block 10	Page 2	

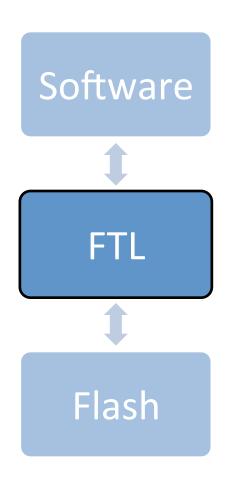
Write Point



Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	15	5	False
1	True	7	0	-	False
2	False	0	4	9	False

Read



1. Read Data at LBA 2k

2. Map

LBA	Physical Page Address		
0	Block 5	Page 7	
2k	Block 27	Page 0	
4k	Block 10	Page 2	

3. Flash Operation

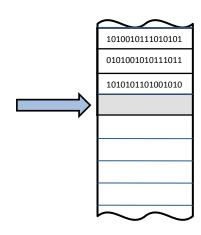
Write – Mid Block

Write 0101101011001010 to LBA 2k

Write Point = Block 2, Page 5

Map

Physical Page Address		
Block 5	Page 7	
Block 0 Page 0		
Block 10 Page 2		
	Block 5 Block 0	



Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	15	5	False
1	True	7	0	-	False
2	False	0	4	9	False

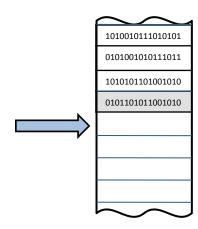
Write – Mid Block

Write 0101101011001010 to LBA 2k

Write Point = Block 2, Page 5 Page 6

Map

LBA	Physical Page Address		
0	Block 5 Page 7		
2k	Block ⊕ 2	Page ⊕ 5	
4k	Block 10 Page 2		



Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	15 14	5	False
1	True	7	0	1	False
2	False	0	4 5	9	False

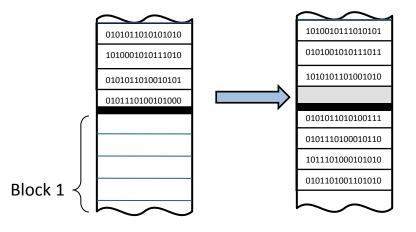
Write – Block Jump (1)

Write 0101001010100110 to LBA 2k

Write Point = Block 2, Page 63

Map

LBA	Physical Page Address		
0	Block 5	Page 7	
2k	Block 0	Page 5	
4k	Block 0 Page 2		
71	Block U Page 2		



Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	15	5	False
1	True	7	0	-	False
2	False	0	4	9	False

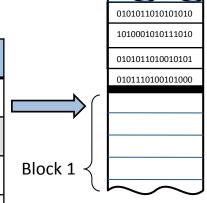
Write – Block Jump (1)

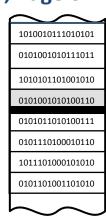
Write 0101001010100110 to LBA 2k

Write Point = Block 2, Page 63 Block 1, Page 0



LBA	Physical Page Address		
0	Block 5	Page 7	
2k	Block ⊕ 2	Page § 63	
4k	Block 0	Page 2	





Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	15 14	5	False
1	True	7	0	-	False
2	False	0	4 5	9	False

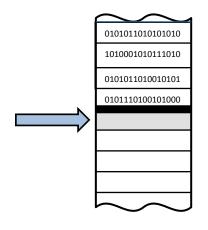
Write – Block Jump (2)

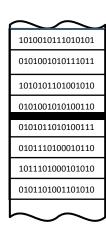
Write 1101000101101001 to LBA 4k

Write Point = Block 1, Page 0

Map

LBA	Physical Page Address		
0	Block 5	Page 7	
2k	Block 2	Page 63	
4k	Block 0 Page 2		





Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator		
0	False	3	14	5	False		
1	True	7	0	-	False		
2	False	0	5	9	False		

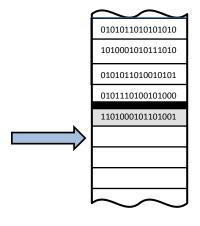
Write – Block Jump (2)

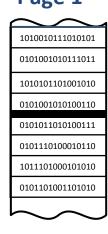
Write 1101000101101001 to LBA 4k

Write Point = Block 1, Page 0
Page 1

Map

	Physical Page Address			
0	Block 5 Page 7			
2k	Block 2	Page 63		
4k	Block ⊕ 1 Page ⊋ 0			





Next Sequence Number: 12 13

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	14 13	5	False
1	∓F	7	0 1	12	False
2	False	0	5	9	False

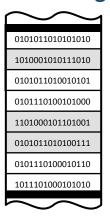
Erase

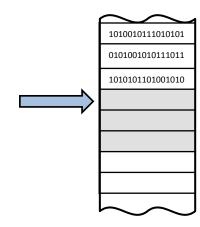
Block Info Table

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	13	5	False
1	False	7	1	12	False
2	False	0	3	9	False

Move Valid Pages

Block 2





Erase

Block Info Table

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	13	5	False
1	False	7	1	12	False
2	False	0	3 0	9	False

Move Valid Pages

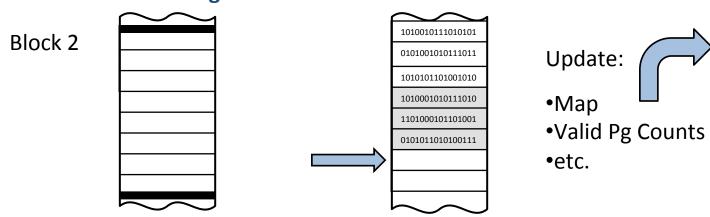
Block 2 Update: •Map •Valid Pg Counts •etc.

Erase

Block Info Table

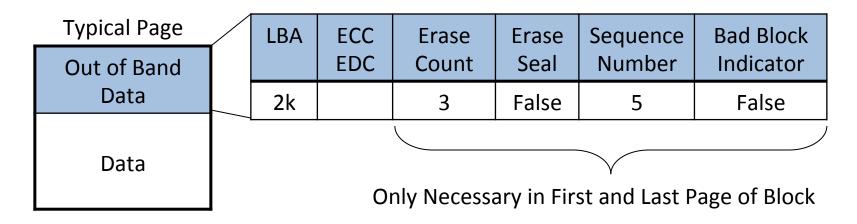
Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator
0	False	3	13	5	False
1	False	7	1	12	False
2	₽T	⊕1	0	-	False

Move Valid Pages



Distributed FTL State

Metadata



Summary Page

Typical Block	_	Physical	Logical Block
Page 0		Page	
Page 1		Page	Address
Page 2		0	10k
:		1	32k
		2	14k
Page n			

Power Cycle

Map

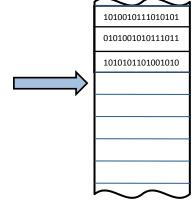
1. Summary page

Scan each block:

- 2. First Page
- 3. All Pages

LBA	Physical Page Address				
0	Block 5	Page 7			
2k	Block 27	Page 0			
4k	Block 10	Page 2			





Next Sequence Number: 12

Block	Erased	Erase Count	Valid Page Count	Sequence Number	Bad Block Indicator		
0	False	3	15	5	False		
1	True	7	0	0	False		
2	False	0	4	9	False		